## FSDH0265RN, FSDM0265RN Green Mode Fairchild Power Switch (FPS ${ }^{\text {TM }}$ )

## Features

- Internal Avalanche Rugged Sense FET
- Consumes only 0.65 W at 240 VAC \& 0.3 W load with Advanced Burst-Mode Operation
- Frequency Modulation for EMI Reduction
- Precision Fixed Operating Frequency
- Internal Start-up Circuit
- Pulse-by-Pulse Current Limiting
- Abnormal Over Current Protection (AOCP)
- Over Voltage Protection (OVP)
- Over Load Protection (OLP)
- Internal Thermal Shutdown Function (TSD)
- Auto-Restart Mode
- Under Voltage Lockout (UVLO)
- Low Operating Current (3mA)
- Adjustable Peak Current Limit
- Built-in Soft Start


## Applications

- SMPS for VCR, SVR, STB, DVD \& DVCD Player
- SMPS for Printer, Facsimile \& Scanner
- Adapter for Camcorder


## Related Application Notes

- AN-4137, 4141, 4147(Flyback) / AN-4134(Forward)


## Description

Each product in the FSDx0265RN (x for M, H) family consists of an integrated Pulse Width Modulator (PWM) and Sense FET, and is specifically designed for high performance off-line Switch Mode Power Supplies (SMPS) with minimal external components. Both devices are integrated high voltage power switching regulators which combine an avalanche rugged Sense FET with a current mode PWM control block. The integrated PWM controller features include: a fixed oscillator with frequency modulation for reduced EMI, Under Voltage Lock Out (UVLO) protection, Leading Edge Blanking (LEB), an optimized gate turn-on/ turn-off driver, Thermal Shut Down (TSD) protection, Abnormal Over Current Protection (AOCP) and temperature compensated precision current sources for loop compensation and fault protection circuitry. When compared to a discrete MOSFET and controller or RCC switching converter solution, the FSDx0265RN devices reduce total component count, design size, weight while increasing efficiency, productivity and system reliability. Both devices provide a basic platform that is well suited for the design of cost-effective flyback converters.

| OUTPUT POWER TABLE |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| PRODUCT | $230 \mathrm{VAC} \pm 15 \%^{(3)}$ |  | $85-265 \mathrm{VAC}$ |  |
|  | Adapt- <br> er $^{(1)}$ | Open <br> Frame $^{(2)}$ | Adapt- <br> er $^{(1)}$ | Open <br> Frame $^{(2)}$ |
|  | 11 W | 17 W | 8 W | 12 W |
| FSDH321 | 11 W | 17 W | 8 W | 12 W |
| FSDL0165RN | 13 W | 23 W | 11 W | 17 W |
| FSDM0265RN | 16 W | 27 W | 13 W | 20 W |
| FSDH0265RN | 16 W | 27 W | 13 W | 20 W |
| FSDL0365RN | 19 W | 30 W | 16 W | 24 W |
| FSDM0365RN | 19 W | 30 W | 16 W | 24 W |
| FSDL321L | 11 W | 17 W | 8 W | 12 W |
| FSDH321L | 11 W | 17 W | 8 W | 12 W |
| FSDL0165RL | 13 W | 23 W | 11 W | 17 W |
| FSDM0265RL | 16 W | 27 W | 13 W | 20 W |
| FSDH0265RL | 16 W | 27 W | 13 W | 20 W |
| FSDL0365RL | 19 W | 30 W | 16 W | 24 W |
| FSDM0365RL | 19 W | 30 W | 16 W | 24 W |

## Notes:

1. Typical continuous power in a non-ventilated enclosed adapter with sufficient drain pattern as a heat sinker, at $50^{\circ} \mathrm{C}$ ambient.
2. Maximum practical continuous power in an open frame design with sufficient drain pattern as a heat sinker, at $50^{\circ} \mathrm{C}$ ambient.
3. 230 VAC or $100 / 115$ VAC with doubler.

## Typical Circuit



Figure 1. Typical Flyback Application

## Internal Block Diagram



Figure 2. Functional Block Diagram of FSDx0265RN

## Pin Definitions

| Pin Number | Pin Name | Pin Function Description |
| :---: | :---: | :--- |
| 1 | GND | Sense FET source terminal on primary side and internal control ground. |
| 2 | Vcc | Positive supply voltage input. Although connected to an auxiliary transform- <br> er winding, current is supplied from pin 5 (Vstr) via an internal switch during <br> startup (see Internal Block Diagram section). It is not until Vcc reaches the <br> UVLO upper threshold (12V) that the internal start-up switch opens and de- <br> vice power is supplied via the auxiliary transformer winding. |
| 3 | Vfb | The feedback voltage pin is the non-inverting input to the PWM comparator. <br> It has a 0.9mA current source connected internally while a capacitor and op- <br> tocoupler are typically connected externally. A feedback voltage of 6V trig- <br> gers over load protection (OLP). There is a time delay while charging <br> external capacitor Cfb from 3V to 6V using an internal 5uA current source. <br> This time delay prevents false triggering under transient conditions, but still <br> allows the protection mechanism to operate under true overload conditions. |
| 4 | Ipk | This pin adjusts the peak current limit of the Sense FET. The feedback <br> $0.9 m A ~ c u r r e n t ~ s o u r c e ~ i s ~ d i v e r t e d ~ t o ~ t h e ~ p a r a l l e l ~ c o m b i n a t i o n ~ o f ~ a n ~ i n t e r n a l ~$ |
| $2.8 \mathrm{k} \Omega$ resistor and any external resistor to GND on this pin to determine the |  |  |
| peak current limit. If this pin is tied to Vcc or left floating, the typical peak cur- |  |  |
| rent limit will be 1.5A. |  |  |

## Pin Configuration



Figure 3. Pin Configuration (Top View)

## Absolute Maximum Ratings

( $\mathrm{Ta}=25^{\circ} \mathrm{C}$, unless otherwise specified)

| Characteristic | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Drain Pin Voltage | VDRAIN | 650 | V |
| Vstr Pin Voltage | VSTR | 650 | V |
| Drain Current Pulsed ${ }^{(1)}$ | IDM | 8.0 | A |
| Single Pulsed Avalanche Energy ${ }^{(2)}$ | EAS | 68 | mJ |
| Supply Voltage | VCC | 20 | V |
| Feedback Voltage Range | VFB | -0.3 to VCC | V |
| Total Power Dissipation | PD | 1.56 | W |
| Operating Junction Temperature | TJ | Internally limited | ${ }^{\circ} \mathrm{C}$ |
| Operating Ambient Temperature | TA | -25 to +85 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | TSTG | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

## Note:

1. Repetitive rating: Pulse width is limited by maximum junction temperature
2. $\mathrm{L}=51 \mathrm{mH}$, starting $\mathrm{Tj}=25^{\circ} \mathrm{C}$

## Thermal Impedance

( $\mathrm{Ta}=25^{\circ} \mathrm{C}$, unless otherwise specified)

| Parameter | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| 8DIP |  |  |  |
| Junction-to-Ambient Thermal ${ }^{(1)}$ | $\theta \mathrm{JA}$ | 79.64 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction-to-Case Thermal ${ }^{(2)}$ | $\theta \mathrm{Jc}$ | 18.20 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction-to-Top Thermal ${ }^{(3)}$ | $\psi J T$ | 34.30 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## Note:

1. Free standing with no heatsink; Without copper clad.
/ Measurement Condition : Just before junction temperature TJ enters into OTP.
2. Measured on the DRAIN pin close to plastic interface.
3. Measured on the PKG top surface.

- all items are tested with the standards JESD 51-2 and 51-10 (DIP).


## Electrical Characteristics

( $\mathrm{Ta}=25^{\circ} \mathrm{C}$ unless otherwise specified)

| Parameter | Symbol | Condition | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SENSE FET SECTION |  |  |  |  |  |  |
| Zero-Gate-Voltage Drain Current | IDSS | VDS $=650 \mathrm{~V}, \mathrm{VGS}=0 \mathrm{~V}$ | - | - | 50 | $\mu \mathrm{A}$ |
|  |  | $\begin{aligned} & \text { VDS }=520 \mathrm{~V}, \mathrm{VGS}=0 \mathrm{~V}, \\ & \mathrm{TC}=125^{\circ} \mathrm{C} \end{aligned}$ | - | - | 200 | $\mu \mathrm{A}$ |
| Drain-Source On-State Resistance ${ }^{(1)}$ | RDS(ON) | VGS $=10 \mathrm{~V}, \mathrm{ID}=0.5 \mathrm{~A}$ | - | 5.0 | 6.0 | $\Omega$ |
| Input Capacitance | CISS | $\begin{aligned} & \text { VGS=0V, VDS }=25 \mathrm{~V}, \\ & \mathrm{f}=1 \mathrm{MHz} \end{aligned}$ | - | 550 | - | pF |
| Output Capacitance | Coss |  | - | 38 | - | pF |
| Reverse Transfer Capacitance | CRSS |  | - | 17 | - | pF |
| Turn-On Delay Time | td(on) | $\mathrm{V} D S=325 \mathrm{~V}, \mathrm{ID}=1.0 \mathrm{~A}$ | - | 20 | - | ns |
| Rise Time | tr |  | - | 15 | - | ns |
| Turn-Off Delay Time | td(off) |  | - | 55 | - | ns |
| Fall Time | tf |  | - | 25 | - | ns |
| CONTROL SECTION |  |  |  |  |  |  |
| Switching Frequency | fosc | FSDH0265R | 92 | 100 | 108 | KHz |
| Switching Frequency Modulation | $\Delta \mathrm{fmOD}$ |  | $\pm 2.0$ | $\pm 3.0$ | $\pm 4.0$ | KHz |
| Switching Frequency | fosc | FSDM0265R | 61 | 67 | 73 | KHz |
| Switching Frequency Modulation | $\triangle \mathrm{fmOD}$ |  | $\pm 1.5$ | $\pm 2.0$ | $\pm 2.5$ | KHz |
| Switching Frequency Variation ${ }^{(2)}$ | $\Delta \mathrm{fOSC}$ | $-25^{\circ} \mathrm{C} \leq \mathrm{Ta} \leq 85^{\circ} \mathrm{C}$ | - | $\pm 5$ | $\pm 10$ | \% |
| Maximum Duty Cycle | Dmax | FSDH0265R | 71 | 77 | 83 | \% |
|  |  | FSDM0265R | 62 | 67 | 72 | \% |
| Minimum Duty Cycle | Dmin |  | 0 | 0 | 0 | \% |
| UVLO Threshold Voltage | Vstart | $\mathrm{V}_{\mathrm{FB}}=\mathrm{GND}$ | 11 | 12 | 13 | V |
|  | VSTOP | $V_{F B}=G N D$ | 7 | 8 | 9 | V |
| Feedback Source Current | IFB | $\mathrm{V}_{\mathrm{FB}}=\mathrm{GND}$ | 0.7 | 0.9 | 1.1 | mA |
| Internal Soft Start Time | ts/s | VFB=4V | 10 | 15 | 20 | ms |
| BURST MODE SECTION |  |  |  |  |  |  |
| Burst Mode Voltage | VBURH | - | 0.4 | 0.5 | 0.6 | V |
|  | VBURL | - | 0.25 | 0.35 | 0.45 | V |
| PROTECTION SECTION |  |  |  |  |  |  |
| Peak Current Limit | ILIM | Max. inductor current | 1.3 | 1.5 | 1.7 | A |
| Current Limit Delay Time ${ }^{(3)}$ | tCLD |  | - | 500 | - | ns |
| Thermal Shutdown Temperature | TSD | - | 125 | 140 | - | ${ }^{\circ} \mathrm{C}$ |
| Shutdown Feedback Voltage | VSD |  | 5.5 | 6.0 | 6.5 | V |
| Over Voltage Protection | Vovp |  | 18 | 19 | - | V |
| Shutdown Delay Current | IDELAY | VFB=4V | 3.5 | 5.0 | 6.5 | $\mu \mathrm{A}$ |
| Leading Edge Blanking Time | tLEB |  | 200 | - | - | ns |
| TOTAL DEVICE SECTION |  |  |  |  |  |  |
| Operating Supply Current (control part only) | IOP | VCC= 14 V | 1 | 3 | 5 | mA |
| Start-Up Charging Current | ICH | Vcc=0V | 0.7 | 0.85 | 1.0 | mA |
| Vstr Supply Voltage | VSTR | $\mathrm{Vcc}=0 \mathrm{~V}$ | 35 | - | - | V |

## Note:

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## Comparison Between KA5x0265RN and FSDx0265RN

| Function | KA5x0265RN | FSDx0265RN | FSDx0265RN Advantages |
| :---: | :---: | :---: | :---: |
| Soft-Start | not applicable | 15ms | - Gradually increasing current limit during soft-start further reduces peak current and voltage stresses <br> - Eliminates external components used for soft-start in most applications <br> - Reduces or eliminates output overshoot |
| External Current Limit | not applicable | Programmable of default current limit | - Smaller transformer <br> - Allows power limiting (constant overload power) <br> - Allows use of larger device for lower losses and higher efficiency. |
| Frequency Modulation | not applicable | $\begin{aligned} & \pm 2.0 \mathrm{KHz} @ 67 \mathrm{KHz} \\ & \pm 3.0 \mathrm{KHz} @ 100 \mathrm{KHz} \end{aligned}$ | - Reduces conducted EMI |
| Burst Mode Operation | not applicable | Built into controller | - Improves light load efficiency <br> - Reduces power consumption at noload <br> - Transformer audible noise reduction |
| Drain Creepage at Package | 1.02mm | 7.62mm | - Greater immunity to arcing provoked by dust, debris and other contaminants |

## Typical Performance Characteristics (Control Part)

(These characteristic graphs are normalized at $\mathrm{Ta}=25^{\circ} \mathrm{C}$ )


Operating Frequency (Fosc) vs. Ta


Maximum Duty Cycle (DMAX) vs. Ta


Start Threshold Voltage (VSTART) vs. Ta


Frequency Modulation ( $\triangle$ FMOD) vs. Ta


Operating Supply Current (IOP) vs. Ta


Stop Threshold Voltage (VSTOP) vs. Ta

Typical Performance Characteristics (Continued)


Feedback Source Current (IFB) vs. Ta


Peak Current Limit (ILIM) vs. Ta


Over Voltage Protection (VOVP) vs. Ta


Start Up Charging Current (ICH) vs. Ta


Burst Peak Current (IBUR(pk)) vs. Ta

## Functional Description

1. Startup : In previous generations of Fairchild Power Switches ( $\mathrm{FPS}^{\mathrm{TM}}$ ) the Vstr pin had an external resistor to the DC input voltage line. In this generation the startup resistor is replaced by an internal high voltage current source and a switch that shuts off when 15 ms goes by after the supply voltage, Vcc, gets above 12 V . The source turns back on if Vcc drops below 8 V .


Figure 4. High Voltage Current Source
2. Feedback Control : The FSDx0265RN employs current mode control, as shown in Figure 5. An opto-coupler (such as the H11A817A) and shunt regulator (such as the KA431) are typically used to implement the feedback network. Comparing the feedback voltage with the voltage across the Rsense resistor plus an offset voltage makes it possible to control the switching duty cycle. When the KA431 reference pin voltage exceeds the internal reference voltage of 2.5 V , the optocoupler LED current increases, the feedback voltage Vfb is pulled down and it reduces the duty cycle. This event typically happens when the input voltage is increased or the output load is decreased.


Figure 5. Pulse Width Modulation (PWM) Circuit
3. Leading Edge Blanking (LEB) : At the instant the internal Sense FET is turned on, the primary side capacitance and secondary side rectifier diode reverse recovery typically cause a high current spike through the Sense FET. Excessive voltage across the Rsense resistor leads to incorrect feedback operation in the current mode PWM control. To counter this effect, the FPS employs a leading edge blanking (LEB) circuit. This circuit inhibits the PWM comparator for a short time (tLEB) after the Sense FET is turned on.
4. Protection Circuits : The FPS has several protective functions such as over load protection (OLP), over voltage protection (OVP), abnormal over current protection (AOCP), under voltage lock out (UVLO) and thermal shutdown (TSD). Because these protection circuits are fully integrated inside the IC without external components, the reliability is improved without increasing cost. Once a fault condition occurs, switching is terminated and the Sense FET remains off. This causes Vcc to fall. When Vcc reaches the UVLO stop voltage VSTOP ( 8 V ), the protection is reset and the internal high voltage current source charges the Vcc capacitor via the Vstr pin. When Vcc reaches the UVLO start voltage VSTART (12V), the FPS resumes its normal operation. In this manner, the auto-restart can alternately enable and disable the switching of the power Sense FET until the fault condition is eliminated.
4.1 Over Load Protection (OLP) : Overload is defined as the load current exceeding a pre-set level due to an unexpected event. In this situation, the protection circuit should be activated in order to protect the SMPS. However, even when the SMPS is operating normally, the over load protection (OLP) circuit can be activated during the load transition. In order to avoid this undesired operation, the OLP circuit is designed to be activated after a specified time to determine whether it is a transient situation or an overload situation. In conjunction with the Ipk current limit pin (if used) the current mode feedback path would limit the current in the Sense FET when the maximum PWM duty cycle is attained. If the output consumes more than this maximum power, the output voltage (Vo) decreases below its rating voltage. This reduces the current through the opto-coupler LED, which also reduces the opto-coupler transistor current, thus increasing the feedback voltage (VFB). If VFB exceeds 3V, the feedback input diode is blocked and the 5uA current source (IDELAY) starts to charge Cfb slowly up to Vcc. In this condition, VFB increases until it reaches 6V, when the switching operation is terminated as shown in Figure 6. The shutdown delay time is the time required to charge Cfb from 3 V to 6 V with $5 u A$ current source.


Figure 6. Over Load Protection (OLP)
4.2 Thermal Shutdown (TSD) : The Sense FET and the control IC are integrated, making it easier for the control IC to detect the temperature of the Sense FET. When the temperature exceeds approximately $140^{\circ} \mathrm{C}$, thermal shutdown is activated.
4.3 Abnormal Over Current Protection (AOCP) : Even though the FPS has OLP (Over Load Protection) and current mode PWM feedback, these are not enough to protect the FPS when a secondary side diode short or a transformer pin short occurs. In addition to start-up, soft-start is also activated at each restart attempt during auto-restart and when restarting after latch mode is activated. The FPS has an internal AOCP (Abnormal Over Current Protection) circuit, as shown in Figure 7. When the gate turn-on signal is applied to the power Sense FET, the AOCP block is enabled and monitors the current through the sensing resistor. The voltage across the resistor is then compared with a preset AOCP level. If the sensing resistor voltage is greater than the AOCP level, pulse-by-pulse AOCP is triggered regardless of uncontrollable LEB time. Here, pulse-by-pulse AOCP stops the Sense FET within 350 ns after it is activated.


Figure 7. Abnormal Over Current Protection (AOCP)
4.4 Over Voltage Protection (OVP) : In the event of a malfunction in the secondary side feedback circuit, or an open feedback loop caused by a soldering defect, the current through the opto-coupler transistor becomes almost zero (refer to Figure 5). Then, VFB climbs up in a similar manner to the over load situation, forcing the preset maximum current to be supplied to the SMPS until the over load protection is activated. Because excess energy is provided to the output, the output voltage may exceed the rated voltage before the over load protection is activated, resulting in the breakdown of the devices in the secondary side. In order to prevent this situation, an over voltage protection (OVP) circuit is employed. In general, Vcc is proportional to the output voltage and the FPS uses Vcc instead of directly monitoring the output voltage. If VCC exceeds 19 V , OVP circuit is activated resulting in termination of the switching operation. In order to avoid undesired activation of OVP during normal operation, Vcc should be properly designed to be below 19 V .
5. Soft Start : The FPS has an internal soft start circuit that slowly increases the feedback voltage together with the Sense FET current after it starts up. The typical soft start time is 15 msec , as shown in Figure 8, where progressive increments of the Sense FET current are allowed during the start-up phase. The pulse width to the power switching device is progressively increased to establish the correct working conditions for transformers, inductors, and capacitors. The voltage on the output capacitors is progressively increased with the intention of smoothly establishing the required output voltage. It also helps to prevent transformer saturation and reduce the stress on the secondary diode.


Figure 8. Soft Start Function
6. Burst Operation : In order to minimize power dissipation in standby mode, the FPS enters burst mode operation. As the load decreases, the feedback voltage decreases. As shown in Figure 9, the device automatically enters burst mode when the feedback voltage drops below VBURH $(500 \mathrm{mV})$. Switching still continues but the current limit is set to a fixed limit internally to minimize flux density in the transformer. The fixed current limit is larger than that defined by VFB $=$ VBURH and therefore, VFB is driven down further. Switching continues until the feedback voltage drops below VBURL $(350 \mathrm{mV})$. At this point switching stops and the output voltages start to drop at a rate dependent on the standby current load. This causes the feedback voltage to rise. Once it passes VBURH $(500 \mathrm{mV})$, switching resumes. The feedback voltage then falls and the process repeats. Burst mode operation alternately enables and disables switching of the power Sense FET thereby reducing switching loss in Standby mode.


Figure 9. Burst Operation Function
7. Frequency Modulation : Modulating the switching frequency of a switched power supply can reduce EMI. Frequency modulation can reduce EMI by spreading the energy over a wider frequency range than the bandwidth measured by the EMI test equipment. The amount of EMI reduction is directly related to the depth of the reference frequency. As can be seen in Figure 10, the frequency changes from 65 KHz to 69 KHz in 4 ms for the FSDM0265RN $(97 \mathrm{KHz}$ to 103 KHz for FSDH0265RN). Frequency modulation allows the use of a cost effective inductor instead of an AC input mode choke to satisfy the requirements of world wide EMI limits.



Figure 10. Frequency Modulation Waveform


Figure 11. KA5-series FPS Full Range EMI scan( 67 KHz , no Frequency Modulation) with DVD Player SET


Figure 12. FSDX-series FPS Full Range EMI Scan ( 67 KHz , with Frequency Modulation) with DVD Player SET
8. Adjusting Peak Current Limit : As shown in Figure 13, a combined $2.8 \mathrm{k} \Omega$ internal resistance is connected to the non-inverting lead on the PWM comparator. A external resistance of Rx on the current limit pin forms a parallel resistance with the $2.8 \mathrm{k} \Omega$ when the internal diodes are biased by the main current source of 900 uA .


Figure 13. Peak Current Limit Adjustment

For example, FSDx0265RN has a typical Sense FET peak current limit (ILIM) of 1.5 A . ILIM can be adjusted to 1 A by inserting Rx between the Ipk pin and the ground. The value of the Rx can be estimated by the following equations:
$1.5 \mathrm{~A}: 1 \mathrm{~A}=2.8 \mathrm{k} \Omega: \mathrm{Xk} \Omega$,
$\mathrm{X}=\mathrm{Rx} \| 2.8 \mathrm{k} \Omega$.
( X represents the resistance of the parallel network)

## Application Tips

## 1. Methods of Reducing Audible Noise

Switching mode power converters have electronic and magnetic components, which generate audible noises when the operating frequency is in the range of $20 \sim 20,000 \mathrm{~Hz}$. Even though they operate above 20 kHz , they can make noise depending on the load condition. Designers can employ several methods to reduce these noises. Here are three of these methods:

## Glue or Varnish

The most common method involves using glue or varnish to tighten magnetic components. The motion of core, bobbin and coil and the chattering or magnetostriction of core can cause the transformer to produce audible noise. The use of rigid glue and varnish helps reduce the transformer noise. But, it also can crack the core. This is because sudden changes in the ambient temperature cause the core and the glue to expand or shrink in a different ratio according to the temperature.

## Ceramic Capacitor

Using a film capacitor instead of a ceramic capacitor as a snubber capacitor is another noise reduction solution. Some dielectric materials show a piezoelectric effect depending on the electric field intensity. Hence, a snubber capacitor becomes one of the most significant sources of audible noise. It is considerable to use a zener clamp circuit instead of an RCD snubber for higher efficiency as well as lower audible noise.

## Adjusting Sound Frequency

Moving the fundamental frequency of noise out of $2 \sim 4 \mathrm{kHz}$ range is the third method. Generally, humans are more sensitive to noise in the range of $2 \sim 4 \mathrm{kHz}$. When the fundamental frequency of noise is located in this range, one perceives the noise as louder although the noise intensity level is identical. Refer to Figure 14. Equal Loudness Curves.
When FPS acts in Burst mode and the Burst operation is suspected to be a source of noise, this method may be helpful. If the frequency of Burst mode operation lies in the range of $2 \sim 4 \mathrm{kHz}$, adjusting feedback loop can shift the Burst operation frequency. In order to reduce the Burst operation frequency, increase a feedback gain capacitor ( CF ), opto-coupler supply resistor ( $\mathrm{R}_{\mathrm{D}}$ ) and feedback capacitor $(\mathrm{CB})$ and decrease a feedback gain resistor $(\mathrm{RF})$ as shown in Figure 15. Typical Feedback Network of FPS.


Figure 14. Equal Loudness Curves


Figure 15. Typical Feedback Network of FPS

## 2. Other Reference Materials

AN-4134: Design Guidelines for Off-line Forward Converters Using Fairchild Power Switch (FPS ${ }^{\mathrm{TM}}$ )

AN-4137: Design Guidelines for Off-line Flyback Converters Using Fairchild Power Switch (FPS)

AN-4140: Transformer Design Consideration for Off-line Flyback Converters using Fairchild Power Switch ( $\mathrm{FPS}^{\mathrm{TM}}$ )

AN-4141: Troubleshooting and Design Tips for Fairchild Power Switch (FPS ${ }^{\text {TM }}$ ) Flyback Applications

AN-4147: Design Guidelines for RCD Snubber of Flyback
AN-4148: Audible Noise Reduction Techniques for FPS Applications

## Typical Application Circuit

| Application | Output power | Input voltage | Output voltage (Max current) |
| :---: | :---: | :---: | :---: |
| DVD Player |  |  | $3.3 \mathrm{~V}(0.8 \mathrm{~A})$ |
|  |  | Universal input | $5.1 \mathrm{~V}(0.4 \mathrm{~A})$ |
|  |  | $(85-265 \mathrm{Vac})$ | $12 \mathrm{~V}(0.3 \mathrm{~A})$ |
|  |  |  | $16 \mathrm{~V}(0.3 \mathrm{~A})$ |

## Features

- High efficiency ( $>76 \%$ at universal input)
- Low standby mode power consumption ( $<1 \mathrm{~W}$ at 230 Vac input and 0.5 W load)
- Low component count
- Enhanced system reliability through various protection functions
- Low EMI through frequency modulation
- Internal soft-start ( 15 ms )


## Key Design Notes

- The delay time for over load protection is designed to be about 30 ms with C106 of 47 nF . If faster/slower triggering of OLP is required, C106 can be changed to a smaller/larger value(eg. 100 nF for about 60 ms ).
- Using a resistor R104(3.3kR) on Ipk pin (\#4), the pule-by-pulse peak current limit level(ILIM) is adjusted to about 0.8A.
- The branch formed by D103, C108 and R106 provides another ILIM adjustment having a negative slope to the input voltage. The ILIM value decreases as the input voltage level increases.


## 1. Schematic


2. Transformer Schematic Diagram


## 3. Winding Specification

|  | Pin(S $\rightarrow$ F) | Wire | Turns | Winding Method |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{N}_{\mathrm{p}} / 2$ | $3 \rightarrow 2$ | $0.25 \varphi \times 1$ | 50 | Center Solenoid winding |
| Insulation: Polyester Tape $\mathrm{t}=0.050 \mathrm{~mm}, 2$ Layers |  |  |  |  |
| $\mathrm{N}_{3.3 \mathrm{~V}}$ | $9 \rightarrow 8$ | $0.33 \varphi \times 2$ | 4 | Center Solenoid winding |
| Insulation: Polyester Tape $\mathrm{t}=0.050 \mathrm{~mm}$, 2 Layers |  |  |  |  |
| $\mathrm{N}_{5.1 \mathrm{~V}}$ | $6 \rightarrow 9$ | $0.33 \varphi \times 1$ | 2 | Center Solenoid winding |
| Insulation: Polyester Tape t $=0.050 \mathrm{~mm}$, 2 Layers |  |  |  |  |
| $\mathrm{Na}^{\text {a }}$ | $4 \rightarrow 5$ | $0.25 \varphi \times 1$ | 16 | Center Solenoid winding |
| Insulation: Polyester Tape t $=0.050 \mathrm{~mm}$, 2 Layers |  |  |  |  |
| $\mathrm{N}_{12 \mathrm{~V}}$ | $10 \rightarrow 12$ | $0.33 \varphi \times 1$ | 14 | Center Solenoid winding |
| Insulation: Polyester Tape $\mathrm{t}=0.050 \mathrm{~mm}$, 3Layers |  |  |  |  |
| $\mathrm{N}_{16 \mathrm{~V}}$ | $11 \rightarrow 12$ | $0.33 \varphi \times 1$ | 18 | Center Solenoid winding |
| Insulation: Polyester Tape $\mathrm{t}=0.050 \mathrm{~mm}$, 2Layers |  |  |  |  |
| $\mathrm{N}_{\mathrm{p}} / 2$ | $2 \rightarrow 1$ | $0.25 \varphi \times 1$ | 50 | Center Solenoid winding |
| Insulation: Polyester Tape t $=0.050 \mathrm{~mm}, 2$ Layers |  |  |  |  |

4. Electrical Characteristics

|  | Pin | Spec. | Remark |
| :---: | :---: | :---: | :---: |
| Inductance | $1-3$ | $1.4 \mathrm{mH} \pm 10 \%$ | $100 \mathrm{kHz}, 1 \mathrm{~V}$ |
| Leakage | $1-3$ | 25 uHMax. | Shortallother pins |

## 5. Core \& Bobbin

Core : EER2828 ( $\mathrm{Ae}=86.66 \mathrm{~mm}^{2}$ )
Bobbin : EER2828
6. Demo Circuit Part List

| Part | Value | Note | Part | Value | Note |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Resistor |  |  | Inductor |  |  |
| R102 | 56K | 1W | L203 | 10uH | - |
| R103 | 5 | 1/4W | L205 | 10uH | - |
| R104 | 3.3K | 1/4W | L206 | 4.7uH | - |
| R105 | 200K | 1/4W | L207 | 4.7uH | - |
| R106 | 300K | 1/4W | Diode |  |  |
| R201 | 510 | 1/4W | D101 | UF4007 | PN Ultra Fast |
| R202 | 1K | 1/4W | D102 | UF4004 | PN Ultra Fast |
| R203 | 6.2 K | 1/4W | D103 | UF4004 | PN Ultra Fast |
| R204 | 20K | 1/4W | D203 | EGP20D | PN Ultra Fast |
| R205 | 6K | 1/4W | D204 | EGP20D | PN Ultra Fast |
| Capacitor |  |  | D205 | SB360 | Schottky |
| C101 | 100nF/275AC | Box | D207 | SB360 | Schottky |
| C102 | 100nF/275AC | Box | IC |  |  |
| C103 | 47uF/400V | Electrolytic | IC101 | FSDH0265RN | FPS ${ }^{\text {TM }}$ |
| C104 | $3.3 \mathrm{nF} / 630 \mathrm{~V}$ | Film | IC301 | KA431(TL431) | Voltage reference |
| C106 | 47uF/50V | Electrolytic | IC302 | FOD817A | Opto-Coupler |
| C107 | 47nF/50V | Ceramic |  |  |  |
| C108 | 1uF/100V | Electrolytic | Fuse |  |  |
| C205 | 470uF/35V | Electrolytic | FUSE | 2A/250V |  |
| C206 | 470uF/35V | Electrolytic |  |  |  |
| C207 | 470uF/35V | Electrolytic | NTC |  |  |
| C208 | 470uF/35V | Electrolytic | RT101 | 5D-9 |  |
| C209 | 1000uF/10V | Electrolytic |  |  |  |
| C210 | 1000uF/10V | Electrolytic | Bridge Diode |  |  |
| C213 | 1000uF/10V | Electrolytic | BD101 | 2KBP06M 2N257 | Bridge Diode |
| C214 | 1000uF/10V | Electrolytic |  |  |  |
| C215 | $100 \mathrm{nF} / 50 \mathrm{~V}$ | Ceramic | Line Filter |  |  |
| C302 | 2.2nF | AC Ceramic | LF101 | 55 mH | - |

7. Layout
7.1 Top image of PCB


### 7.2 Bottom image of PCB



## Package Dimensions

## 8DIP



## NOTES: UNLESS OTHERWISE SPECIFIED

A) THIS PACKAGE CONFORMS TO

JEDEC MS-001 VARIATION BA
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
D) DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994

MKT-NO8FrevB

Package Dimensions (Continued)

## 8LSOP



NOTES: UNLESS OTHERWISE SPECIFIED
A) THIS PACKAGE DOESNOT CONFORM TO ANY CURRENT PACKAGE STANDARD
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
D) DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994
$\frac{\text { DETAIL A }}{\text { SCALE: } 2 \mathrm{X}}$

## Ordering Information

| Product Number | Package | Marking Code | BVDSS | fosc | RDS(ON) |
| :---: | :---: | :---: | :---: | :---: | :---: |
| FSDM0265RN | 8DIP | DM0265R | 650 V | 67 KHz | $5.0 \Omega$ |
| FSDH0265RN | 8DIP | DH0265R | 650 V | 100 KHz | $5.0 \Omega$ |
| FSDM0265RL | 8LSOP | DM0265R | 650 V | 67 KHz | $5.0 \Omega$ |
| FSDH0265RL | 8LSOP | DH0265R | 650 V | 100 KHz | $5.0 \Omega$ |

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1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

[^0]:    1. Pulse test: Pulse width $\leq 300$ us, duty $\leq 2 \%$
    2. These parameters, although guaranteed, are tested in EDS (wafer test) process
    3. These parameters, although guaranteed, are not $100 \%$ tested in production
